

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2	"20060220634"	US-PGPUB; USPAT; JPO	ADJ	ON	2008/01/23 08:21
L2	5845	327/530,538-543,545,546.ccls.	US-PGPUB; USPAT; JPO	ADJ	ON	2008/01/23 10:51
L3	1291	257/197.ccls.	US-PGPUB; USPAT; JPO	ADJ	ON	2008/01/23 10:51
L4	2	"20060220634"	US-PGPUB; USPAT; JPO	ADJ	ON	2008/01/23 12:34
S2	0	(band adj gap bandgap) adj2 (reference voltage circuit\$2) \$2TAT	US-PGPUB; USPAT	ADJ	ON	2008/01/18 08:36
S3	63241	(band adj gap bandgap) adj2 (reference voltage circuit\$2) \$2TAT	US-PGPUB; USPAT	OR	ON	2008/01/18 08:36
S4	6654	(band adj gap bandgap) adj2 (reference voltage circuit\$2) \$2TAT and 327/538,538.ccls.	US-PGPUB; USPAT	OR	ON	2008/01/18 08:37
S5	862016	(band adj gap bandgap) adj2 (reference voltage circuit\$2) \$2TAT and voltage generation circuit and 327/538,538.ccls.	US-PGPUB; USPAT	OR	ON	2008/01/18 08:37
S6	0	(band adj gap bandgap) adj2 (reference voltage circuit\$2) \$2TAT and voltage generation circuit and 327/538,538.ccls.	US-PGPUB; USPAT	ADJ	ON	2008/01/18 08:37
S7	234	((band adj gap bandgap) adj2 (reference voltage circuit\$2) \$2TAT) and 327/538,538.ccls.	US-PGPUB; USPAT	OR	ON	2008/01/18 08:38
S8	975	((band adj gap bandgap) adj2 (reference voltage circuit\$2) \$2TAT) and 327/530,538,539,540- 543,545,546.ccls.	US-PGPUB; USPAT	OR	ON	2008/01/18 11:15
S9	0	("2007/0164809").URPN.	USPAT	ADJ	ON	2008/01/18 12:06
S10	4091	fukuda.in.	USPAT	ADJ	ON	2008/01/18 12:07

S11	26	fukuda.in. and "327".clas.	USPAT	ADJ	ON	2008/01/18 12:07
S12	1082112	voltage generat\$4 and 327/530,538,539,540- 543,545,546.ccls.	US- PGPUB; USPAT	OR	ON	2008/01/18 12:58
S13	1082094	voltage generat\$4 and (second transistor) and 327/530,538,539,540- 543,545,546.ccls.	US- PGPUB; USPAT	OR	ON	2008/01/18 12:59
S14	637	voltage generat\$4 and (second transistor) and 327/530,538,539,540- 543,545,546.ccls.	US- PGPUB; USPAT	ADJ	ON	2008/01/18 13:00
S15	0	voltage generat\$4 and (second transistor and fourth resistor) and 327/530,538,539,540- 543,545,546.ccls.	US- PGPUB; USPAT	ADJ	ON	2008/01/18 13:00
S16	68	voltage generat\$4 and (second transistor and fourth resistor) and 327/530,538,539,540- 543,545,546.ccls.	US- PGPUB; USPAT	ADJ	ON	2008/01/18 13:02
S17	0	("2006/0208790").URPN.	USPAT	ADJ	ON	2008/01/18 13:11
S18	1	("2003/0006831").URPN.	USPAT	ADJ	ON	2008/01/18 13:22
S19	1	"20030006831"	US- PGPUB; USPAT	ADJ	ON	2008/01/22 08:25
S20	65	coady.in.	US- PGPUB; USPAT	ADJ	ON	2008/01/22 08:25
S21	7	coady.in. and "327".clas.	US- PGPUB; USPAT	ADJ	ON	2008/01/22 08:26
S22	4651	(differential amplifier or op amp) near5 (CMOS or MOS or MOSFET or PMOS or NMOS or PMOSFET or NMOSFET)	US- PGPUB; USPAT	ADJ	ON	2008/01/22 10:50
S23	2255	(differential amplifier or op amp) near2 (CMOS or MOS or MOSFET or PMOS or NMOS or PMOSFET or NMOSFET)	US- PGPUB; USPAT	ADJ	ON	2008/01/22 10:53
S24	887	(differential amplifier or op amp) near2 (CMOS or MOS or MOSFET or PMOS or NMOS or PMOSFET or NMOSFET) and substrate	US- PGPUB; USPAT	ADJ	ON	2008/01/22 10:55
S25	341	(differential amplifier or op amp) near2 (CMOS or MOS or MOSFET or PMOS or NMOS or PMOSFET or NMOSFET) and semiconductor substrate	US- PGPUB; USPAT	ADJ	ON	2008/01/22 10:57

S26	0	(differential amplifier or op amp) near2 (CMOS or MOS or MOSFET or PMOS or NMOS or PMOSFET or NMOSFET) near "10" semiconductor substrate	US-PGPUB; USPAT	ADJ	ON	2008/01/22 10:57
S27	3	(differential amplifier or op amp) near2 (CMOS or MOS or MOSFET or PMOS or NMOS or PMOSFET or NMOSFET) near10 semiconductor substrate	US-PGPUB; USPAT	ADJ	ON	2008/01/22 10:58
S28	134	(differential amplifier or op amp) near2 (CMOS or MOS or MOSFET or PMOS or NMOS or PMOSFET or NMOSFET) and diffusion layer	US-PGPUB; USPAT	ADJ	ON	2008/01/22 11:03
S29	0	("2007/0052405").URPN.	USPAT	ADJ	ON	2008/01/22 11:11
S30	2	"2005258870"	US-PGPUB; USPAT; JPO	ADJ	ON	2008/01/22 11:13
S31	0	first transistor near5 unit transistor	US-PGPUB; USPAT; JPO	ADJ	ON	2008/01/22 15:30
S32	0	transistor near5 unit near "5" parallel	US-PGPUB; USPAT; JPO	ADJ	ON	2008/01/22 15:30
S33	802	transistor near5 unit near5 parallel	US-PGPUB; USPAT; JPO	ADJ	ON	2008/01/22 15:31
S34	275	(transistor near5 unit near5 parallel) same plural\$4	US-PGPUB; USPAT; JPO	ADJ	ON	2008/01/22 15:31

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